# DATA SHEET

# SILICON POWER TRANSISTORS 2SA1615, 1615-Z

# PNP SILICON EPITAXIAL TRANSISTOR FOR HIGH-SPEED SWITCHING

The 2SA1615 and 1615-Z are available for the large current control in small dimension due to the low saturation and are ideal for high-efficiency DC/DC converters due to the fast switching speed.

#### **FEATURES**

NEC

- · Large current capacity: IC(DC): -10 A, IC(pulse): -15 A
- High hFE and low collector saturation voltage:  $h_{FE} = 200 \text{ MIN.}$  (@Vce = -2.0 V, Ic = -0.5 A)  $V_{CE(sat)} \le -0.25 \text{ V}$  (@Ic = -4.0 A, IB = -0.05 A)

#### QUALITY GRADES

Standard

ices<sup>3</sup> Please refer to "Quality Grades on NEC Semiconductor Devices" (Document No. C11531E) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

# ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

Parameter	Symbol	Ratings	Unit
Collector to base voltage	Vсво	-30	V
Collector to emitter voltage	Vceo	-20	V
Emitter to base voltage	Vebo	-10	v
Collector current (DC)	IC(DC)	-10	А
Collector current (pulse)	IC(pulse)*	-15	А
Base current (DC)	B(DC)	-0.5	А
Total power dissipation	P⊤ (Ta = 25°C)**	1.0	W
Total power dissipation	P⊤ (T₀ = 25°C)	15	W
Junction temperature	Tj	150	°C
Storage temperature	Tstg	–55 to +150	°C

\* PW  $\leq$  10 ms, duty cycle  $\leq$  50%

\*\* Printing board mounted

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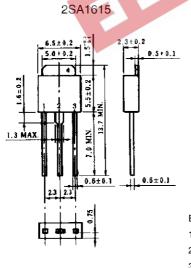
Parameter Sym		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current		Ісво	$V_{CB} = -20 \text{ V}, \text{ I}_{E} = 0$			-1.0	μA
Emitter cutoff current		Іево	$V_{EB} = -8.0 \text{ V}, \text{ Ic} = 0$			-1.0	μΑ
DC current gain		hfe1*	$V_{CE} = -2.0 \text{ V}, \text{ Ic} = -0.5 \text{ A}$	200		600	
DC current gain		hfe2*	Vce = -2.0 V, Ic = -4.0 A	160			
Collector saturation voltage		V <sub>CE(sat)</sub> *	Ic = -4.0 A, I <sub>B</sub> = -0.05 A		-0.2	-0.25	V
Base saturatio	on voltage	V <sub>BE(sat)</sub> *	Ic = -4.0 A, I <sub>B</sub> = -0.05 A		-0.9	-1.2	V
Gain bandwid	th product	f⊤	Vce = -5.0 V, Ie = 1.5 A		180		MHz
Output capaci	ty	Cob	$V_{CB} = -10 \text{ V}, \text{ I}_{E} = 0, \text{ f} = 1.0 \text{ MHz}$		220		pF
Turn-on time		ton	$I_{C} = -5.0 \text{ A}, I_{B1} = -I_{B2} = 0.125 \text{ A},$		80		ns
Storage time		tstg	$R_L = 2.0 \Omega$ , $V_{CC} \simeq -10 V$		300		ns
Fall time		tr			60		ns
* Pulse test $PW \le 350 \ \mu s$ , duty cycle $\le 2\%$ hFE CLASSIFICATION Marking L K hFE2 200 to 400 300 to 600							
Marking	L		К				
hfe2	200 to 400	) 3	300 to 600				
PACKAGE DRAWING (UNIT: mm)							

## **ELECTRICAL CHARACTERISTICS (Ta = 25°C)**

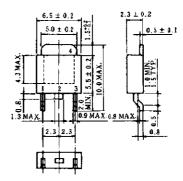
### **hfe CLASSIFICATION**

Marking	L	к	
hfe2	200 to 400	300 to 600	

# PACKAGE DRAWING (UNIT: mm)



2SA1615-Z

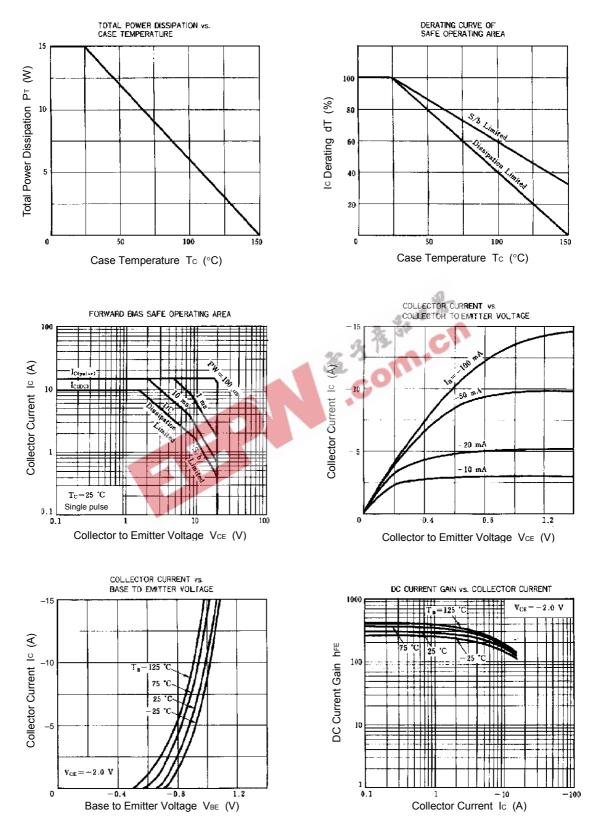


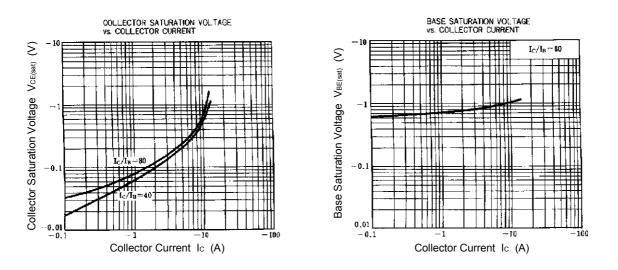
Electrode Connection

- 1. Base
- 2. Collector
- 3. Emitter
- 4. Collector (fin)

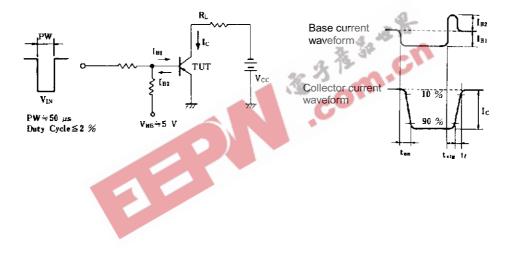


#### TYPICAL CHARACTERISTICS (Ta = 25 °C)





SWITCHING TIME (ton, tstg, tf) TEST CIRCUIT



[MEMO]



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